# Intel<sup>®</sup> Server Board SE7210TP1-E Memory List Test Report Summary



Revision 6.0 June, 2004

Revision	History	
Date	Rev	Modifications
Jan/04	.5	Pre-release
Feb/04	1.0	Release document. Added Micron 128MB & 256MB parts. Added Infineon 256MB, 512MB & 1G parts.
Feb/04	1.1	Added Infineon 128MB & 1G parts. Added Micron 256MB & 512MB parts. Added Samsung 512MB part.
Mar/04	2.0	Added TRS 256MB and 512MB parts. Added Smart and Avant 1GB parts. (In shaded area)
Mar/04	3.0	Added ATP and Dataram 256MB parts. Added ATP, Dataram, Ventura and Smart 512MB parts. Added Avant 1GB parts. (In shaded area)
Apr/04	4.0	Added Buffalo 256MB, 512MB, and 1GB parts. Added Legend and ATP 256MB parts. Added Ventura 512MB parts. (In shaded area)
May/04	5.0	Added Viking 256MB and 512MB parts. Added Avant, Legend, Micron, Smart, and Legacy 512MB parts. Added ATP & Infineon 1GB parts. (In shaded area)
Jun/04	6.0	Added Avant 256MB part. Added Simple, Transcend and Legend 512MB parts. Added TRS and Legend 1GB parts. (In shaded area)

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The Intel® Server Board SE7210TP1-E may contain design defects or errors known as errata which may cause the product to deviate from published specifications. Current characterized errata are available on request.

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**Please Note:** DIMM devices with gold contacts should NOT be placed into DIMM sockets with tinlead contacts or vice-versa. Mixing dissimilar metal contact types has been shown to result in unreliable memory operation. Intel recommends similar manufacturer and similar speeds in each bank on the memory module. Mixing of dissimilar memory manufacturer and similar speeds in each bank on the memory module is NOT recommended

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### **Overview of Memory Testing**

The following procedure is used to test memory modules for use in the Intel<sup>®</sup> Server Board SE7210TP1-E. Memory is a vital subsystem in a platform. Intel Corporation requires strict guidelines to be met before a memory vendor and part is put onto the qualified memory list. Each Intel Server Board product has a separate qualified memory list.

Memory qualification for Intel's Server Board products is performed by Intel's Memory Validation Laboratory (MVL), and by an independent external test laboratory, Computer Memory Test Lab (CMTL)<sup>1</sup>. CMTL is a leading memory testing organization responsible for testing a broad range of memory products. Memory devices tested by Intel's MVL or CMTL must undergo rigorous tests to ensure that the product will perform the intended server functions.

Intel<sup>®</sup>'s Server and Workstation Board qualified memory lists categorize memory modules as Advanced Tested. The Advanced Testing process involves a paper qualification, a standard voltage and room temperature functional test, and a voltage and temperature margin functional test. A paper qualification is a review of critical timings, electrical characteristics, timing requirements, environmental requirements, and packaging requirements in order to see if the memory meets Intel's memory specifications. The standard voltage and room temperature test involves testing the memory module on the particular Intel board for which it is being qualified with test software operating under Microsoft\* Windows\* 2000 Advanced Server for no less than 24 hours. The voltage and temperature margin testing involves testing the memory module on the particular Intel board for which it is being qualified with various test software and operating systems for 48-72 hours under various voltage and temperature margin conditions. Memory modules that have completed Advanced Testing are known to be compatible with the product on which they were tested, and with the test software and operating system that was utilized during the test procedure.

For information regarding the testing procedure required to reach each phase, please contact your Intel Representative.

<sup>1</sup> CMTL is an independent memory testing organization responsible for testing a broad range of memory products. Receiving a "PASS" after being tested by CMTL, means that a product functions correctly and consumers can use it to perform the intended server functions. In order to pass these stringent standards, memory products must maintain the highest manufacturing procedures and pass an exacting battery of tests. Testing is performed with equipment and a procedure as defined by Intel's various functional testing levels. CMTL contact:

Office: (949) 716-8690 Fax (949) 716-8691 Computer Memory Test Lab (CMTL) 24 Hammond Suite F Irvine, CA 92618 http://www.cmtlabs.com/

## Qualified Memory for the Intel® Server Board SE7210TP1-E

The memory module on the server board SE7210TP1-E has 4 DIMM sockets, which can hold up to 4 GB of Unbuffered ECC and non-ECC DDR266, DDR333 or DDR400 memory using four 72-bit DIMM modules. The following memory features are supported:

- DDR266, DDR333 and DDR400 Unbuffered ECC and non-ECC compatible 2.5V modules (in compliance with the DDR JEDEC DIMM Specification)
- DIMMs with capacity of 128MB, 256 MB, 512 MB, 1G. Other DRAM sizes may function correctly but will not be validated.
- Minimum configuration is 128MB using one 128MB DIMM.

Below is a chart that lists the current supported memory types:

DDR	266, DDR3	<b>33, and</b> ]	<b>DDR400 U</b>	<b>nbuffered SD</b>	RAM Module						
	Matrix										
DIMM Capacity	DIMM Organization	SDRAM Density	SDRAM Organization	#SDRAM Devices/rows/Banks	# Address bits rows/Banks/column						
128MB	16M x 72	128Mbit	16M x 8	9/1/4	12/2/10						
256MB	32M x 72	128Mbit	16M x 8	18/2/4	12/2/10						
256MB	32M x 72	256Mbit	32M x 8	9/1/4	13/2/10						
512MB	64M x 72	256Mbit	32M x 8	18/2/4	13/2/10						
512MB	64M x 72	512Mbit	64M x 8	9/1/4	13/2/11						
1GB	128M x 72	512Mbit	64M x 8	18/2/4	13/2/11						

Memory features are detailed in *the Intel<sup>®</sup>* Server Board SE7210TP1-E Technical Product Specification available on-line at <u>http://support.intel.com/support/motherboards/server/SE7210TP1-E</u>

The following table lists DIMM devices known to be compatible with the Intel Server Board SE7210TP1-E. Intel recommends that Advanced Tested DIMMs be used to establish reliable system operation. DIMM devices not listed can be used; but, in the event of unreliable system operation, the DIMM devices should be replaced with functionally Advanced Tested DIMMs to determine whether the DIMM devices are causing the problem.

**Caution:** Third party memory vendors may use the same module part number with different DRAM vendors and die revisions. To insure proper system operation, verify that each DRAM vendor and die revision has been separately tested and qualified. Please notify CMTL if there is a discrepancy.

**Note**: This list is not intended be all-inclusive. It is provided as a convenience to Intel's general customer base, but Intel does not make any representations or warranties whatsoever regarding the quality, reliability, functionality, or compatibility of these memory modules.

This list is subject to change without notice.

		Server B	oard Si	E7210T	Р1-Е				
		Unbuffered, E 1281	-	266 DIMN (16Mx72)	1 Module	es			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
Infineon	HYS72D16000GU- 7-A	HYB250D128800AT -7A	Infineon		2/23/04	2	Yes	(16Mx8)*9	
Manufacturer	Part Number	Unbuffered, E 1281 DRAM Part Number		(16Mx72) PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
		Unbuffered, E 128		400 DIMM (16Mx72)	l Module	es			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
Micron	MT5VDDT1672AG- 40BC3	MT46V16M16-5B C	Micron		1/27/04	3	Y	(16Mx8)*9	

(+) This vendor is part of the CMTL Certification program. This means this part has/will been tested across all compatible Intel Server Boards. For further information contact CMTL @ <a href="http://cmtlabs.com/">http://cmtlabs.com/</a>

		Ser	ver Board	l SE7210	TP1-E	E			
		Unbuffere	ed, Non-ECC 128MB Si	, DDR266 D zes (16Mx72		dules			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
		Unbuffere	ed, Non-ECC	•		dules			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	zes (16Mx72 PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
		Unbuffere	ed, Non-ECC 128MB Si	, DDR400 D zes (16Mx72		dules			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL

(+) This vendor is part of the CMTL Certification program. This means this part has/will been tested across all compatible Intel Server Boards. For further information contact CMTL @ http://cmtlabs.com/

	Server Boo	urd SE	7210TI	P1-E				
L				Module	S			
Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
M381L3223ETM-CA2	K4H560838E-TCA2	Samsung		1/19/04	2	Y	(32Mx8)*9	
HYS72D32000GU-7-A	HYB25D256800AT- 7A	Infineon		1/27/04	2	Y	(32Mx8)*9	
MT9VDDT3272AG- 265B1	MT46V32M8-75 B	Micron		2/9/04	2.5	Y	(32Mx8)*9	
MT9VDDT3272AG- 265C4	MT46V32M8-75 C	Micron		2/23/04	2.5	Y	(32Mx8)*9	
L		•		Module	S			
Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
MT9VDDT3272AG- 335C4	MT46V32M8-6TC	Micron		1/12/04	2.5	Y	(32Mx8)*9	
HYS72D32300HU-6-C	HYB25D256800CE- 6	Infineon		2/9/04	2.5	Y	(32Mx8)*9	
AG32L72T8SQB3S	K4H560838F-TCB3 rev F	Samsung	SG184T08 L1	3/12/04	2.5	Y	(32Mx8)*9	
L3272DC7- DR1HDC9B	HY5DU56822BT- D43 rev B	Hyundai	DR720818 C1 rev 1	3/17/04	3	Y	(32Mx8)*9	
AG32L72T8SQC4S	K4H560838F- TCCC rev F	Samsung	SG184T08 L1 rev 1	3/19/04	3	Y	(32Mx8)*9	
AVM7232U39C5333K4- A	MT46V32M8TG(P)- 6T rev G	Micron	50-1402- 01-B rev B	5/25/04	2.5	Y	(32Mx8)*9	
		•		Module	es			
Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile		EOL
HYS72D32300GU-5-B	5B	Infineon		1/12/04	3	Y	(32Mx8)*9	
M381L3223ETM-CCC	K4H560838E- TCCC	Samsung		1/18/04	3	Y	(32Mx8)*9	
MT18VDDT3272AG- 40BB5	MT46V16M8-5B	Micron		2/23/04	3	Y	(16Mx8)*18	
TRS20172	HYB25D256800BT- 5 rev B	Infineon	M0534LA1 rev 1	2/20/04	3	Y	(32Mx8)*9	
DTM63671B	HYB25D256800BT- 5 rev B	Infineon	40570 rev A	3/8/04	3	Y	(32Mx8)*9	
VI4CU327228DTPL2	V58C2256804SAT5 B rev B	Mosel Vitelic	0000981A	5/6/04	3	Y	(32Mx8)*9	
	Part Number   M381L3223ETM-CA2   HYS72D32000GU-7-A   MT9VDDT3272AG-265B1   MT9VDDT3272AG-265C4   MT9VDDT3272AG-265C4   MT9VDDT3272AG-265C4   MT9VDDT3272AG-265C4   MT9VDDT3272AG-265C4   AG32L72T8SQB3S   AG32L72T8SQB3S   AG32L72T8SQC4S   AUM7232U39C5333K4-A   A   MT18VDDT3272AG-40BES   M381L3223ETM-CCCC   MT18VDDT3272AG-40BES   A0BB5   TRS20172	Part Number   DRAM Part Number     M381L3223ETM-CA2   K4H560838E-TCA2     HYS72D32000GU-7-A   HYB25D256800AT- 7A     MT9VDDT3272AG- 265B1   MT46V32M8-75 B     MT9VDDT3272AG- 265C4   MT46V32M8-75 C     MT9VDDT3272AG- 265C4   MT46V32M8-75 C     Part Number   DRAM Part Number     MT9VDDT3272AG- 335C4   MT46V32M8-6TC     MT9VDDT3272AG- 335C4   MT46V32M8-6TC     HYS72D32300HU-6-C   6     AG32L72T8SQB3S   K4H560838F-TCB3 rev F     L3272DC7- DR1HDC9B   D43 rev B     AG32L72T8SQC4S   K4H560838F- TCCC rev F     AVM7232U39C5333K4- AC32L72T8SQC4S   MT46V32M8TG(P)- 6T rev G     AVM7232U39C5333K4- AC32L72T8SQC4S   MT46V32M8TG(P)- 6T rev G     Part Number   DRAM Part Number     HYS72D32300GU-5-B   HYB25D256800BT- 5B     M381L3223ETM-CCC   K4H560838E- TCCC     MT8VDDT3272AG- 40BB5   MT46V16M8-5B     MT8VDDT3272AG- 40BB5   HYB25D256800BT- 5rev B     MT46V16M8-5B   HYB25D256800BT- 5 rev B     VI4CU1327228DTP1 2   V58C2256804SAT5	Unbuffered, ECC, DDR2G 256MB Sizes (3)Part NumberDRAM Part NumberDRAM vendorM381L3223ETM-CA2K4H560838E-TCA2SamsungHYS72D32000GU-7-AHYB25D256800AT- 7AInfineonMT9VDDT3272AG- 265B1MT46V32M8-75 BMicronMT9VDDT3272AG- 265C4MT46V32M8-75 CMicronWT9VDDT3272AG- 265C4MT46V32M8-75 CMicronWT9VDDT3272AG- 265C4MT46V32M8-75 CMicronWT9VDDT3272AG- 335C4MT46V32M8-6TCMicronMT9VDDT3272AG- 335C4MT46V32M8-6TCMicronHYS72D32300HU-6-CHYB25D256800CE- 6InfineonAG32L72T8SQB3SK4H560838F-TCB3 rev FSamsungL3272DC7- DR1HDC9BHYS10DT6822BT- D43 rev BHyundaiAG32L72T8SQC4SK4H560838F- TCCC rev FSamsungAVM7232U39C5333K4MT46V32M8TG(P)- 6T rev GMicronHYS72D32300GU-5-BPRAM Part Number SEDRAM vendorHYS72D32300GU-5-BHYB25D256800BT- 5BInfineonM381L3223ETM-CCCK4H560838E- TCCCSamsungM18VDT3272AG- A0BB5MT46V16M8-5BMicronM381L3223ETM-CCCK4H560838E- TCCCSamsungM18VDT3272AG- A0BB5MT46V16M8-5BMicronM381L3223ETM-CCCK4H560838E- TCCCSamsungM18VDT3272AG- A0BB5MT46V16M8-5BMicronM18VDT3272AG- A0BB5MT46V16M8-5BMicronM18VDT3272AG- A0BB5MT46V16M8-5BMicronM18VDT3272AG- A0BB	Unbuffered, ECC, DDR266 DIMM 2 256MB Sizes (32MX72)Part NumberDRAM Part NumberDRAM vendorNumberM381L3223ETM-CA2K4H560838E-TCA2SamsungHYS72D32000GU-7-AHYB25D256800AT- 7AInfineonMT9VDDT3272AG- 265B1MT46V32M8-75 BMicronMT9VDDT3272AG- 265C4MT46V32M8-75 CMicronUnbuffered, ECC, DDR333 DIMM 256MB Sizes (32MX72)Part NumberDRAM Part Number VendorPCB Part NumberMT9VDDT3272AG- 335C4MT46V32M8-6TCMicronMT9VDDT3272AG- 335C4Mt46V32M8-6TCMicronHYS72D32300HU-6-CHYB25D256800CE- 6InfineonAG32L72T8SQB3SK4H560838F-TCB3 rev FSamsungSG184T08 C1 rev 1L3272DC7- DR1HDC9BD43 rev BSG184T08 C1 rev 1L1 NumberAVM7232U39C533K4- A G32L72T8SQC4SK4H560838F- TCCC rev FSamsungSG184T08 L1 rev 1LVMD213272DC7- AOTDUffered, ECC, DDR4UDIMM DIMMDUrbuffered, ECC, DDR4UDIMM Sizes (32MX72)Part NumberDRAM Part Number SBDRAM C1 rev 1HYS72D32300GU-5-BSBSamsungSG184T08 C1 rev 1M381L3223ETM-CCCK4H560838E- TCCCSamsungC1 MicronM18VDDT3272AG- 40BB5MY825D256800BT- SBInfineonM381L3223ETM-CCCK4H560838E- TCCCSamsungM18VDDT3272AG- 40BB5MY825D256800BT- SBInfineonM180VDT3272AG- 40BB5MY825D256800BT- Srev B <td>Sizes (32Mx72)     Part Number   DRAM Part Number Vendor   PCB Part Number   Date Number     M381L3223ETM-CA2   K4H560838E-TCA2   Samsung   1/19/04     HYS72D32000GU-7-A   HYB25D25680A7- 7A   Infineon   1/27/04     MT9VDDT3272AG- 265B1   MT46V32M8-75 B   Micron   2/23/04     MT9VDDT3272AG- 265C4   MT46V32M8-75 C   Micron   2/23/04     MT9VDDT3272AG- 265C4   MT46V32M8-75 C   Micron   2/23/04     MT9VDDT3272AG- 265C4   MT46V32M8-75 C   Micron   2/23/04     MT9VDDT3272AG- 335C4   MT46V32M8-6TC   Micron   PCB Part Number   Date     MT9VDDT3272AG- 335C4   MT46V32M8-6TC   Micron   1/12/04   1/12/04     HYS72D32300HU-6-C   HYB25D256800CE- 6   Infineon   2/9/04   3/12/04     L3272DC7- DR1HDC9B   HYB25D256803EF- TCC rev F   Samsung   SG184T08   3/12/04     AG32L72T8SQC4S   K4H560838F- TCC rev F   Samsung   SG184T08   3/19/04     AVM7232U39C5333K4- A   MT46V32M8TG(P)- 6T rev G   Micron   50-1402- 01-B rev B   50-1402- 01-B rev B</td> <td>Unbuffered, ECC, DDR266 DIMM Modules 256MB Sizes (32MX72)     Part Number   DRAM Part Number Vendor   PCB Part Number   Date   CAS Latency     M381L3223ETM-CA2   K4H560838E-TCA2   Samsung   1/19/04   2     HYS72D32000GU-7-A   HYB25D256800AT- 7A   Infineon   1/27/04   2     MT9VDDT3272AG- 265B1   MT46V32M8-75 B   Micron   2/2/3/04   2.5     Unbuffered, ECC, DDR333 DIMM Modules 256MB Sizes (32MX72)   Date   CAS Latency     Part Number   DRAM Part Number   DRAM   PCB Part   Date   CAS Latency     MT9VDDT3272AG- 335C4   MT46V32M8-6TC   Micron   1/12/04   2.5     MT9VDDT3272AG- 335C4   MT46V32M8-6TC   Micron   1/12/04   2.5     HYS72D32300HU-6-C   6   6   3/12/04   2.5     L3272DC7- DR1HDC9B   K4H560838F-TCB3 Samsung   SG184T08   3/12/04   3     AG32L727BSQG4S   K4H560838F- TCCC rev F   Samsung   SG184T08   3/12/04   3     AVM7232U39C5333K4   MT46V32M8TG(P)- MT46V32M8TG(P)- MT46V32M8TG(P)- Micron   Date   CAS Late</br></br></td> <td>Britered, ECC, DDR266 DIMM Modules     Part Number   DRAM Part Number   DRAM   PCB Part   Date   CAS   Low     M381L3223ETM-CA2   K4H560838E-TCA2   Samsung   1/19/04   2   Y     HYS72D32000GU-7-A   HYB25D256800AT- 7A   Infineon   1/27/04   2   Y     MT9VDDT3272AG- 265C4   MT46V32M8-75 B   Micron   2/23/04   2.5   Y     Unbuffered, ECC, DDR333 DIMM Modules   Z/23/04   2.5   Y     Part Number   DRAM Part Number   DRAM   PCB Part   Date   CAS   Low     Wordor   PCB Part   Date   CAS   Low     MT46V32M8-75 C   Micron   1/12/04   2.5   Y     MT9VDDT3272AG- 335C4   MT46V32M8-6TC   Micron   1/12/04   2.5   Y     AG32L72T8S0B3S   K4H560838F-TCB3   Samsung   SG184T08   3/17/04   3   Y     Ad332L72T8S0B3S   K4H560838F-TCB3   Samsung   SG184T08   3/17/04   3   Y     Ad32L72T8S0B3S   K4H560838F-TCB3&lt;</td> <td>Unbuffered, ECC, DDR266 DIMM Modules     Part Number   DRAM   PCB Part   Date   CAS   Low   DRAM     M381L3223ETM-CA2   K4H560838E-TCA2   Samsung   1/19/04   2   Y   (32Mx8)'9     HYS72D32000GU-7-A   HYB52D256800AT-   Infineon   1/27/04   2   Y   (32Mx8)'9     MT9VDDT3272AG-   Z6561   MT46V32M8-75 B   Micron   2/23/04   2.5   Y   (32Mx8)'9     MT9VDDT3272AG-   MT46V32M8-75 C   Micron   2/23/04   2.5   Y   (32Mx8)'9     MT9VDDT3272AG-   MT46V32M8-75 C   Micron   2/23/04   2.5   Y   (32Mx8)'9     MT9VDDT3272AG-   MT46V32M8-6TC   Micron   1/12/04   2.5   Y   (32Mx8)'9     HYS7ZD32300HU-6-C   HYB25D256800CE-   Infineon   2/9/04   2.5   Y   (32Mx8)'9     HYS7ZD32300HU-6-C   HYB25D258600CE-   Infineon   2/9/04   2.5   Y   (32Mx8)'9     AG32L727BSQB3S   K4H56083F-TCB3   Samsung   SG184T08   3/12/04</td>	Sizes (32Mx72)     Part Number   DRAM Part Number Vendor   PCB Part Number   Date Number     M381L3223ETM-CA2   K4H560838E-TCA2   Samsung   1/19/04     HYS72D32000GU-7-A   HYB25D25680A7- 7A   Infineon   1/27/04     MT9VDDT3272AG- 265B1   MT46V32M8-75 B   Micron   2/23/04     MT9VDDT3272AG- 265C4   MT46V32M8-75 C   Micron   2/23/04     MT9VDDT3272AG- 265C4   MT46V32M8-75 C   Micron   2/23/04     MT9VDDT3272AG- 265C4   MT46V32M8-75 C   Micron   2/23/04     MT9VDDT3272AG- 335C4   MT46V32M8-6TC   Micron   PCB Part Number   Date     MT9VDDT3272AG- 335C4   MT46V32M8-6TC   Micron   1/12/04   1/12/04     HYS72D32300HU-6-C   HYB25D256800CE- 6   Infineon   2/9/04   3/12/04     L3272DC7- DR1HDC9B   HYB25D256803EF- TCC rev F   Samsung   SG184T08   3/12/04     AG32L72T8SQC4S   K4H560838F- TCC rev F   Samsung   SG184T08   3/19/04     AVM7232U39C5333K4- A   MT46V32M8TG(P)- 6T rev G   Micron   50-1402- 01-B rev B   50-1402- 01-B rev B	Unbuffered, ECC, DDR266 DIMM Modules 256MB Sizes (32MX72)     Part Number   DRAM Part Number Vendor   PCB Part Number   Date   CAS Latency     M381L3223ETM-CA2   K4H560838E-TCA2   Samsung   1/19/04   2     HYS72D32000GU-7-A   HYB25D256800AT- 7A   Infineon   1/27/04   2     MT9VDDT3272AG- 265B1   MT46V32M8-75 B   Micron   2/2/3/04   2.5     Unbuffered, ECC, DDR333 DIMM Modules 256MB Sizes (32MX72)   Date   CAS Latency     Part Number   DRAM Part Number   DRAM   PCB Part   Date   CAS Latency     MT9VDDT3272AG- 335C4   MT46V32M8-6TC   Micron   1/12/04   2.5     MT9VDDT3272AG- 335C4   MT46V32M8-6TC   Micron   1/12/04   2.5     HYS72D32300HU-6-C   6   6   3/12/04   2.5     L3272DC7- DR1HDC9B   K4H560838F-TCB3 Samsung   SG184T08   3/12/04   3     AG32L727BSQG4S   K4H560838F- TCCC rev F   Samsung   SG184T08   3/12/04   3     AVM7232U39C5333K4   MT46V32M8TG(P)- MT46V32M8TG(P)- MT46V32M8TG(P)- 	Britered, ECC, DDR266 DIMM Modules     Part Number   DRAM Part Number   DRAM   PCB Part   Date   CAS   Low     M381L3223ETM-CA2   K4H560838E-TCA2   Samsung   1/19/04   2   Y     HYS72D32000GU-7-A   HYB25D256800AT- 7A   Infineon   1/27/04   2   Y     MT9VDDT3272AG- 265C4   MT46V32M8-75 B   Micron   2/23/04   2.5   Y     Unbuffered, ECC, DDR333 DIMM Modules   Z/23/04   2.5   Y     Part Number   DRAM Part Number   DRAM   PCB Part   Date   CAS   Low     Wordor   PCB Part   Date   CAS   Low     MT46V32M8-75 C   Micron   1/12/04   2.5   Y     MT9VDDT3272AG- 335C4   MT46V32M8-6TC   Micron   1/12/04   2.5   Y     AG32L72T8S0B3S   K4H560838F-TCB3   Samsung   SG184T08   3/17/04   3   Y     Ad332L72T8S0B3S   K4H560838F-TCB3   Samsung   SG184T08   3/17/04   3   Y     Ad32L72T8S0B3S   K4H560838F-TCB3<	Unbuffered, ECC, DDR266 DIMM Modules     Part Number   DRAM   PCB Part   Date   CAS   Low   DRAM     M381L3223ETM-CA2   K4H560838E-TCA2   Samsung   1/19/04   2   Y   (32Mx8)'9     HYS72D32000GU-7-A   HYB52D256800AT-   Infineon   1/27/04   2   Y   (32Mx8)'9     MT9VDDT3272AG-   Z6561   MT46V32M8-75 B   Micron   2/23/04   2.5   Y   (32Mx8)'9     MT9VDDT3272AG-   MT46V32M8-75 C   Micron   2/23/04   2.5   Y   (32Mx8)'9     MT9VDDT3272AG-   MT46V32M8-75 C   Micron   2/23/04   2.5   Y   (32Mx8)'9     MT9VDDT3272AG-   MT46V32M8-6TC   Micron   1/12/04   2.5   Y   (32Mx8)'9     HYS7ZD32300HU-6-C   HYB25D256800CE-   Infineon   2/9/04   2.5   Y   (32Mx8)'9     HYS7ZD32300HU-6-C   HYB25D258600CE-   Infineon   2/9/04   2.5   Y   (32Mx8)'9     AG32L727BSQB3S   K4H56083F-TCB3   Samsung   SG184T08   3/12/04

(+) This vendor is part of the CMTL Certification program. This means this part has/will been tested across all compatible Intel Server Boards. For further information contact CMTL @ <a href="http://cmtlabs.com/">http://cmtlabs.com/</a>

		Server 1	Board S	SE7210T	P1-E				
		Unbuffered, No 25		DR266 DIM s (32Mx72)	IM Mo	dules			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
		Unbuffered, No 25		DDR333 DIM s (32Mx72)	IM Mo	dules			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
+Buffalo	DD333-S256/SF	K4H560838F-TCB3 rev F	Samsung	UE0832-AA	4/13/0 4	2.5	Y	(32Mx8)*8	
			6MB Size	s (32Mx72)	IM Mo				
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
+Legend	L3264DC7- BU1HDC9C	HY5DU56822CT- D43 rev C	Hyundai	B6U808 rev 1	4/9/04	3	Y	(32Mx8)*8	
		led in blue are low pro	<b>C</b> 1	1			<u> </u>		

(+) This vendor is part of the CMTL Certification program. This means this part has/will been tested across all compatible Intel Server Boards. For further information contact CMTL @ <u>http://cmtlabs.com/</u>

		Server B	oard SI	E <b>72101</b>	ГР1-Е	,			
	L	Inbuffered, E 512	ECC, DDR MB Sizes			les			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
Micron	MT18VDDT6472AG- 265C4	MT64v32M8-75 C	Micron		2/24/04	2.5	Y	(32Mx8)*18	
Samsung	M381L6423DTL-CA2	K4H560838D- TCA2	Samsung			2	Y	(32Mx8)*18	
	L	Inbuffered, E 512	ECC, DDR MB Sizes			les			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
Infineon	HYS72D64320HU-6-C	HYB25D256800 CE-6C	Infineon		2/2/04	2.5	Y	(32Mx8)*18	
Micron	MT18VDDT6472AG- 335C4	MT46V32M8- 6TC	Micron		2/23/04	2.5	Y	(32Mx8)*18	
+ATP Electronics	AG64L72T8SQB3S	K4H560838F- TCB3 rev F	Samsung	SG184T08 L1	3/12/04	2.5	Y	(32Mx8)*18	
+Ventura Technology Group	D52XVK29SV	K4H560838E- TCB3 rev E	Samsung	V215	3/10/04	2.5	Y	(32Mx8)*18	
+Avant Technology	AVM7264U39C5333K4 -A	MT46V32M8TG( P)-6T rev G	Micron	50-1402- 01-B rev B	4/29/04	2.5	Y	(32Mx8)*18	
	L	Inbuffered, E 512	ECC, DDR MB Sizes			les			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
Micron	MT18VDDT6472AG- 40BC4	MT46V32M8-5B C	Micron		1/24/04	3	Y	(32Mx8)*18	
Micron	MT9VDDT6472AG- 40BC1	MT46V64M8- 5BC	Micron		1/18/04	3	Y	(64Mx8)*9	
+TRS	TRS20173	HYB25D256800 BT-5 rev B	Infineon	M0524LA1 rev 1	2/18/04	3	Y	(32Mx8)*18	
+Smart Modula Technologies	r SM6472DDR2N1	HYB25D256800 BT-5 rev B	Infineon	L-DIM-184- 31-1	3/3/04	3	Y	(32Mx8)*18	
+ATP Electronics	AG64L72T8SQC4S	K4H560838F- TCCC rev F	Samsung	SG184T08 L1	3/8/04	3	Y	(32Mx8)*18	
+Dataram	DTM63672B	HYB25D256800 BT-5 rev B	Infineon	40570 rev A	3/4/04	3	Y	(32Mx8)*18	
+Legend	L6472DC7- DR1HDC9B	HY5DU56822BT -D43 rev B	Hyundai	DR720818 C rev 1	4/19/04	3	Y	(32Mx8)*18	
+Smart Modula Technologies		K4H560838F- TCCC rev F	Samsung	M381L331 3DTM	4/23/04	3	Y	(32Mx8)*18	
+Viking	VI4CU647228DTPL2	V58C2256804S AT5B rev B	Mosel Vitelic		5/4/04	3	Y	(32Mx8)*18	
Micron	MT9VDDT6472AG- 40BD1	MT46V64M8-5B D	Micron		5/3/04	3	Y	(64Mx8)*9	
	40001								

	Unbuffered, ECC, DDR400 DIMM Modules 512MB Sizes (64Mx72)										
Manufacturer	Manufacturer   Part Number   DRAM Part   DRAM   PCB Part   Date   CAS   Low   DRAM   EOL     Number   Vendor   Number   Latency   Profile   Organization   EOL										
SimpleTech	K4H560838E-										
Transcend Information	TS64MLD72V4F3 (HU)	V58C2256804S AT5B	Mosel Vitelic	09-1835	5/24/04	3	Y	(32Mx8)*18			

(+) This vendor is part of the CMTL Certification program. This means this part has/will been tested across all compatible Intel Server Boards. For further information contact CMTL @ <a href="http://cmtlabs.com/">http://cmtlabs.com/</a>

		Server <b>B</b>	Board Si	E7210TI	P1-E				
		Unbuffered, No. 512	n-ECC, DL MB Sizes		M Modi	ules			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
		Unbuffered, No 512	n-ECC, DL MB Sizes		M Modi	ules			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
+Ventura Technology Group	D51XVK29SV	K4H560838E-TCB3 rev E	Samsung	V215	3/19/04	2.5	Y	(32Mx8)*16	
+Buffalo	DD333-512/SF	K4H560838F-TCB3 rev F	Samsung	UE0532-AA	4/13/04	2.5	Y	(32Mx8)*16	
			MB Sizes	(64Mx72)	1				
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
+Legacy Electronics Inc.	88S5HDL0- 1UDG	HYB25D256800BT-5 rev B	Infineon	LE18DDT18 48 rev A	4/19/04	3	Y	(32Mx8)*16	
+Legend	L6464DC7- DE6HDC5B	HY5DU56822BT-D43 rev B	Hyundai	DE640816 A rev 6	5/10/04	3	Y	(32Mx8)*16	
+Legend	L6464DC7- BU1HDC9C	HY5DU56822CT-D43 rev C	Hyundai	B6U808 rev 1	5/27/04	3	Y	(32Mx8)*16	

(+) This vendor is part of the CMTL Certification program. This means this part has/will been tested across all compatible Intel Server Boards. For further information contact CMTL @ <a href="http://cmtlabs.com/">http://cmtlabs.com/</a>

		Comor I	Board SE	771071	D1 E				
		Unbuffered,		66 DIMM		s			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
Infineon	HYS72D128020GU- 7-A	HYB25D512800AT -7A	Infineon		2/9/04	2	Y	(64Mx8)*18	
		Unbuffered, 1G	ECC, DDR3 B Sizes (12		Module	es			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
+Avant Technology	AVM7228U52C5333 K4-A	MT46V64M8TG-5B rev C	Micron	50-1402-01- B rev B	2/27/04	2.5	Y	(64Mx8)*18	
+ATP Electronics	AG28L72T8SHB3S	K4H510838B- TCB3 rev B	Samsung	SG184T08L 1 rev 1	5/6/04	2.5	Y	(64Mx8)*18	
Infineon	HYS72D128320HU- 6-B	HYB25D512800B E-6B	Infineon		4/28/04	2.5	Y	(64Mx8)*18	
		Unbuffered, 10	ECC, DDR4 B Sizes (12		Module	es			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
Micron	MT18VDDT12872AG -40BC1	MT46V64M8-5BC	Micron		1/18/04	3	Y	(64Mx8)*18	
Infineon	HYS72D128320HU- 5-B	HYB25D512800B E-5B	Infineon		2/23/04	3	Y	(64Mx8)*18	
+Smart Modular Technologies	SM12872DDR2N1	K4H510838B- TCCC rev B	Samsung	M381L3313 DTM	2/27/04	3	Y	(64Mx8)*18	
+Avant Technology	AVM7228U52C3400 K4-A	MT46V64M8TG(P)- 5B rev C	Micron	50-1402-01- B rev B	3/10/04	3	Y	(64Mx8)*18	
+ATP Electronics	AG28L72T8SHC4M	MT46V64M8TG(P)- 5B rev C	Micron	SG184T08L 1 rev 1	4/23/04	3	Y	(64Mx8)*18	
+TRS	TRS20193	MT46V64M8TG(P)- 5B rev C	Micron	M0524LA1 rev 1	5/18/04	3	Yes	(64Mx8)*18	

(+) This vendor is part of the CMTL Certification program. This means this part has/will been tested across all compatible Intel Server Boards. For further information contact CMTL @ http://cmtlabs.com/

		Server	Board S	SE7210	TP1-	E			
		Unbuffered, N 1	on-ECC, L GB Sizes			odules			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
		Unbuffered, N 1	on-ECC, I GB Sizes			odules			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
		Unbuffered, N 1	on-ECC, I GB Sizes			odules			
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	CAS Latency	Low Profile	DRAM Organization	EOL
+Buffalo	DD4333-1G/SB	K4H510838B- TCCC rev B	Samsung	UE0532-AA	4/7/04	3	Y	(64Mx8)*16	
+Buffalo	DD4333-1G/MC	MT46V64M8TG(P )-5B rev C	Micron	UE0532-AA	3/17/04	3	Y	(64Mx8)*16	
+ATP Electronics	AG28L64T8SHC4S	K4H510838B- TCCC rev B	Samsung	SG184T08L 1	4/29/04	3	Y	(64Mx8)*16	
+Legend	L1264DC7- DE6HDH9A	HY5DU12822AT- D43 rev A	Hyundai	DE640816 A rev 6	5/12/04	3	Yes	(64Mx8)*16	
+Legend	L1264DC7- BU1HDH9A	HY5DU12822AT- D43 rev A	Hyundai	B6U808 rev 1	6/1/04	3	Yes	(64Mx8)*16	

(+) This vendor is part of the CMTL Certification program. This means this part has/will been tested across all compatible Intel Server Boards. For further information contact CMTL @ http://cmtlabs.com/

## **Sales Information**

Vendor Name	Web URL	Vendor Direct Sales Info
ATP Electronics	http://www.atpusa.com/	Florence Hsieh
		Tel 408-732-5831
		Fax 408-732-5055
		sales@atpusa.com
ATP Electronics	http://www.atpusa.com/	Patty Kuo
Taiwan Inc.		Tel 011-886-2-2659-6368
		Fax 886-2-2659-4982
Avant Technology	http://www.avanttechnology.com	Brad Scoggins
		Phone: (512)491-7411
		Fax: (512)491-7412
		brads@avanttechnology.com
Aved Memory Products	http://www.avedmemory.com/	
Buffalo Technology	http://www.buffalotech.com/	(800) 967-0959
		memory@buffalotech.com
Centon Electronics	http://www.centon.com	Tel: 949-855-9111
		Fax: 949-855-6035
Corsair	http://www.corsairmicro.com/	Tel: 510-657-8747
		Fax: 510-657-8748
Dane-Elec	http://www.dane-memory.com/	Michal Hassan @ (949)450-2941 or email @
		Michal@Dane-memory.com
Dataram	http://www.dataram.com/	Paul Henke, 800-328-2726 x2239 in USA
		phenke@dataram.com
		Peter Jauss, +49-69-680-9070 in EMEA
		pjauss@dataram.com
GoldenRAM	http://www.goldenram.com	Jason M. Barrette @ 800-222-861 x7546
		jasonb@goldenram.com
		or Michael E. Meyer @800-222-8861 x7512
		michaelm@goldenram.com
Hitachi	http://semiconductor.hitachi.com/pointer/	
Hyundai/Hynix	http://www.hea.com/	
Semiconductor		
Infineon	http://www.infineon.com/business/distribut	
	/index.htm	
ITAUCOM	http://www.itaucom.com.br	
JITCO CO LTD	http://www.jitco.net/	Seong Jeon
		Tel: 82-32-817-9740
		s.jeon@jitco.net
Kingston	http://www.kingston.com	US Call (877) 435-8726
0		Asia – Call 886-3-564-1539
		Europe – Call +44-1932-755205
Legacy Electronics Inc.	http://www.legacyelectronics.com	U.S. Contact: Keri Albers 888 466 3853 ext. 307
		European Contact: 49 89 370 664 11
Legend	http://www.legend.com.au	
Micron	http://silicon.micron.com/mktg/http://silico	
	n.micron.com/mktg/mbqual/qual_data.cfm	
MSC Vertriebs GmbH	http://www.msc-ge.com	William Perrigo
		49-7249-910-417
		Fax: 49-7249-910-229
		wpe@msc-ge.com
Netlist, Inc	http://www.netlistinc.com	Christopher Lopes
		949.435.0025 tel
		949.435.0031 fax
		949.455.0051 Tax

Vendor Name	Web URL	Vendor Direct Sales Info
Peripheral Enhancements	http://www.peripheral.com/	
PNY	http://www.pny.com/internet_explorer/LP B.HTML	
Samsung	http://www.korea.samsungsemi.com/locate/ buy/list_na.html	For US customers go to: http://www.mymemorystore.com/
Silicon Tech	http://www.silicontech.com/contact/salesco	
Simple Tech	ntacts.shtml     http://www.simpletech.com	Ron Darwish @ (949) 260-8230 or email @ Rdarwish@Simpletech.com
SMART Modular Technologies	http://www.smartm.com	Leo Alafriz 949-753-0116 ext. 125 leo.alafriz@smartm.com
Swissbit	http://www.swissbit.com	Tony Cerreta Tel: 914-935-1400 x240 Fax: 914-935-9865 tony.cerreta@swissbitna.com
TechnoLinc Corporation	http://www.technolinc.com	David Curtis 510-445-7400 davidc@technolinc.com
TRS* Tele-Radio-Space GmbH	http://www.certified-memory.com http://www.certified-memory.de	Vendor Direct Sales Info: Andreas Gründl, Pho.: +49(0)89/94553234, Fax.: +49(0)89/94553293, agruendl@trs-space.de
Unigen	http://www.unigen.com	
Ventura Technology Inc	http://www.venturatech.com	Don Hummel @ 805-581-0800 x 108 or email @ don@venturatech.com
Viking InterWorks	http://www.vikinginterworks.com	
Virtium Technology Inc	http://www.virtium.com	Tod Skelton @ (949) 460-0020 ext. 146 or email @ tod.skelton@virtium.com
Legend	http://www.legend.com.au	Tel: 800-338-2361 Fax: 949-459-8577 orderdesk@vikingcomponents.com
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#### CMTL\* (Computer Memory Test Labs)

CMTL is a privately owned and operated memory testing organization responsible for testing a broad range of memory products. Memory devices tested by CMTL must undergo a rigorous battery of tests to ensure that the product will perform the intended server functions. Memory capability is a major factor your customers consider. CMTL has the ability to test and certify memory on Intel-based server platforms. The list of memory modules, which have undergone testing through the CMTL facility, should be referenced when considering modules for integration into this Intel server product. Stringent standards with regard to manufacturing procedures and quality must be met to pass the exacting tests required for qualification through the independent testing facility. Testing is performed by CMTL with Intel server products and test procedures defined by Intel's Memory Validation Lab. Intel routinely audits the CMTL facility to ensure all procedures, process handling, and testing methodologies are met.

#### **IMPORTANT NOTE**

DIMM devices with gold contacts should NOT be placed into DIMM sockets with tin-lead contacts or viceversa. Mixing dissimilar metal contact types has been shown to result in unreliable memory operation. Intel recommends similar manufacturer and similar speeds in each bank on the memory module. Mixing of dissimilar memory manufacturer devices or dissimilar memory device speeds is not recommended. This document contains information which is the proprietary property of Intel Corporation. Nothing in this document constitutes a guaranty, warranty, or license, express or implied. Intel has tested the following DIMMs for minimum electrical and functional compatibility with boxed processors. This listing is not intended to be all inclusive; it only represents the DIMMs Intel or CMTL has tested. Users of this list are reminded to check with the DIMM manufacturer or Distributor to ensure that a particular DIMM model is adequate for the intended purpose on the boxed processor baseboard. Intel provides no indemnities for and expressly disclaims all liabilities for any and all such guaranties, representations, and warranties (oral or written) whether express or implied, related to DIMMs in a Intel® Server Board product, including without limitation to: fitness for a particular purpose; merchantability; noninfringement of intellectual property or other rights of any third party or of Intel. The reader is advised that third parties may have intellectual property rights which may be relevant to this document and the technologies discussed herein, and is advised to seek the advice of competent legal counsel, without obligation of Intel. Intel retains the right to make changes to this document at any time, without notice. Intel makes no warranty or representation with respect to the use of this document or reliance by the reader upon its contents, and assumes no responsibility for any errors which may appear in the document nor does it make a commitment to update the information contained herein.

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